

CONTENTS

| | |
|---|-----|
| Foreword | vii |
| Welcoming Speech | ix |
| Synchrotron Radiation Studies of MBE Formed Semiconductor Interfaces: Si-GaAs and GaAs-Si | 1 |
| R. Z. BACHRACH*, R. D. BRINGANS, MARJORIE A. OLMSTEAD & R. I. G. UHRBERG | |
| Band Offsets in Semiconductors – Theoretical Calculations and Models | 14 |
| R. M. MARTIN* | |
| Surface Structural Study by High Resolution UHV-Electron Microscopy and Diffraction | 23 |
| K. TAKAYANAGI* | |
| Evidence of Adatom Clusters in the Si(111) 7 × 7 Surface | 36 |
| W. S. YANG* & R. G. ZHAO | |
| Interaction and Bonding of Bromine on Fe(110) | 44 |
| T. N. RHODIN*, D. R. MUELLER, Y. SAKISAKA & P. A. DOWBEN | |
| Scattering Potentials for Surface Diffraction Spectroscopies | 52 |
| X. J. WU, M. W. PUGA & S. Y. TONG* | |
| Some Aspects of Applied Surface Science in Vacuum Physics Laboratory | 65 |
| HUA ZHONGYI* | |
| Theory of Surface-ion Neutralization | 80 |
| S. G. DAVISON*, K. W. SULSTON & A. T. AMOS | |
| Low Energy Ion Scattering and Its Application to the Analysis of the Composition and Structure of Surfaces | 89 |
| R. J. MacDONALD* | |

| | |
|--|-----|
| Kinetic Processes at Equilibrium and Non-Equilibrium Surfaces examined via RHEED in Molecular Beam Epitaxy of III–V Semiconductors A. MADHUKAR* | 98 |
| Properties of GaAs/AlGaAs Heterointerface Grown by MBE HUANG YI* & ZHOU JUNMING | 109 |
| Atom Profiling at Epitaxial Co/GaAs Interfaces J. H. WEAVER* | 122 |
| Atomic and Electronic Structures of InP Polar Surfaces XUN WANG* | 131 |
| <i>Ab Initio</i> Calculation of Ground- and Excited-state Properties of Surfaces STEVEN G. LOUIE* | 140 |
| Scanning Tunneling Microscopy: A New Tool for Surface Studies in Vacuum, Liquid and Air Environments M. SALMERON* | 148 |
| Theoretical Studies of Metal Chemisorption on Silicon Surface XIE XIDE* | 162 |
| Macroscopic Properties and Schottky Barrier Formation at Silicide-Silicon Interfaces PAUL S. HO* | 170 |
| Gas Nitrided Austenitic Stainless Steel M. F. CHUNG & Y. K. LIM* | 179 |
| Research of Surface and Interface Physics Group at the Institute of Semiconductors, Academia Sinica XU ZHENJIA (C. C. HSU)* | 190 |
| The $c(4 \times 4)$ Reconstruction on Si(100) Clean Surface HONGCHUAN WANG*, RONGFU LIN & XUN WANG | 199 |
| DVM Cluster Calculation on the Si(111) 7×7 Surface F. WU*, HAN RUSHAN, W. S. YANG & Q. Q. ZHENG | 203 |

| | |
|---|------------|
| The Use of Electron Microscopy to Study Nobel Metal-Silicon Interfaces | 209 |
| M. HANBÜCKEN* | |
| Atom-Adsorbate Interactions | 215 |
| W. K. LIU* | |
| Weak Molecular Adsorption on Metal Surfaces | 222 |
| E. GARFUNKEL* | |
| The Formation and Electronic Structure of Ga/InP(100) Interface | 225 |
| XIAOFENG JIN*, MINGREN YU, FURONG ZHU & XUN WANG | |
| Chemisorption of Ni on GaAs Surface | 230 |
| ZHU ZIZHONG* & ZHANG KAIMING | |
| A Study of Phonon on Semiconductor Surfaces | 235 |
| LIN ZIJING*, WANG KELIN & GU YIMING | |
| A Study of the Effect of Interfacial Defects on GaAs Schottky Barrier | 241 |
| WU FENGMEI*, GONG BANGRUI, ZHOU XINGENG & TANG JIE | |
| Ionization Processes of Atoms Collided with Solid Surfaces | 247 |
| M. TSUKADA* & S. TSUNEYUKI | |
| Structure Studies on LaB₆ Crystals with Angle-Resolved Auger Electron Spectroscopy | 253 |
| BAO SHINING, LIU GU*, BAO DESONG, JI ZHENGUO & CHEN ZENGJI | |
| Electrostatic Field Distribution Adjacent to the Metal Probe Tip and its Effects on Surface States | 259 |
| S. OHNISHI* & Y. CHIBA | |
| Work Function of Submonolayer Alkali-metal Covered W(001) Surface | 265 |
| WU RUQIAN, CHEN KAILAI, WANG DINGSHENG* & WANG NING | |

| | |
|---|-----|
| An Angle-resolved Photoemission Study of the Reaction of CH₃SH and (CH₃S)₂ with Cu(111) and Ni(100) | 271 |
| BAO SHINING*, C. F. McCONVILLE & D. P. WOODRUFF | |
| Studies of Oxygen and Sulfur Segregation on V(100) | 284 |
| HE PEIMO*, LIU GU, JI ZHENGUO & ZHOU XIAOXIA | |
| Studies of Absorption and Segregation by Angle-resolved Auger Electron Spectroscopy | 290 |
| JI ZHENGUO*, LIU GU, BAO DESONG & ZHOU XIAOXIA | |
| Selective Adsorption and Scattering of Hydrogen Molecule on Rigid Copper Surface | 296 |
| XUEYING SHEN* | |
| Impurity Effects on the Change in Density of States during Chemisorption | 305 |
| T. ZHANG* & W. K. LIU | |
| Evidence for s-d Rehybridization in Cu₃ Au | 311 |
| SICHENG WU* | |
| Silicon Molecular Beam Epitaxy on GaP(111) | 317 |
| W. D. JIANG, G. L. ZHOU, K. M. CHEN, C. SHEN, X. J. ZHANG & X. WANG | |
| A Study of X-ray Diffraction Theory for the Amorphous Superlattice with Non-ideal Interface | 324 |
| LIU HONGTU*, HUANG WENYONG, LU XIANGDONG WU ZHIQIANG & JIN HUAICHENG | |
| Analysis of the Single-crystal Fe Films on GaAs Grown by MOCVD | 330 |
| ZHENG YOUDOU*, T. K. KIM & B. D. McCOMBE | |
| Studies of Al₂O₃/InP Interface by AES and XPS | 336 |
| HAN PING*, ZHENG YOUDOU & JIANG ROULIAN | |
| The Chemical Trends of Deep Level in Type-I Semiconductor Superlattices | 342 |
| MINGZHU HUANG, YIMING GU, MINGLIANG CHEN* & SHANGYUAN REN | |

| | |
|--|------------|
| The Correlation Function of Two-dimensional Electron System | 348 |
| YU ENXI, SUN XIN* & QIAN YONGJIA | |
| A Transfer Model for Dealing with Surface Plasmon and Surface Phonon of Semiconducting Superlattice with Quasiperiodic Primary Cell | 354 |
| GUOYI QIN* & YONGSHENG WANG | |
| The Electronic Structure of Metallic Superlattices with Layer Number Disorder | 360 |
| JIANG GUOPING* & XIONG SHIJIE | |
| Surface Properties and Interactions Studied with the Pulsed Laser Atom Probe | 366 |
| T. J. KINKUS | |
| Study of Interface Properties of SOI Structure | 370 |
| HUANG XINFAN*, BAO XIMAO & CHEN JIAN | |
| Structural Study of Si-W and Si-Pd Alloy Film after Annealing | 376 |
| WU ZIQIN*, DUAN JIANZHONG & LU JIANG | |
| A Study of the Properties of Nitrogen Existing in SiO₂-Si Interfacial Region | 382 |
| QI MING* & LUO JINSHENG | |
| Force Analysis to Chemisorptions of Transition Metals on Si(111) Surface | 388 |
| TIAN ZHENGJU*, CHIKATOSHI SATOKO & SHUHEI OHNISHI | |
| Metal Induced Crystallization of α-Si:H | 394 |
| JIN SHU*, LIU HONGTU, ZHAO TEXIU, WU ZIQIANG, SHEN BOU & HSU CHENCHIA | |
| The Role of Oxygen on the Ag Surface for Forming the Alkoxy Studied by Photoacoustic Spectroscopy | 400 |
| M. C. WU, A. R. ZHU & Z. Y. WANG | |
| A Study of Interaction Between Hydrogen and the Surface of W, Mo, Nb and Ta by AP-FIM | 406 |
| CHEN CHONGLIN & REN DAGANG* | |

| | |
|--|------------|
| Photo-electrical Characteristics of Semiconducting Polymer P3MT/Electrolyte Interface and Catalysis of Pt Atoms on P3MT Surface | 412 |
| R. K. YUAN, Z. C. HUANG, D. PERAMUNAGE, W. TOMKIEWICZ & D. S. GINLEY | |
| Correlation Between Surface Spike and Over-cosine Angular Distribution of Sputtered Atoms | 418 |
| LIPING ZHENG*, FUZHAI CUI & ZHENXIA WANG | |
| Two Dimension Phase Transition in Chemisorption System – Monte-Carlo Simulation | 425 |
| HU ZIPU* & LI JIA | |
| Surface Segregation of Some Binary Alloys Studied by a Combined Method of ISS and AES | 430 |
| I. KATAYAMA*, F. SHOJI, K. OURA & T. HANAWA | |
| Ion-bombardment-enhanced Diffusion Phenomenon of Pb-Sn Alloy | 436 |
| QIANGJI ZHANG*, YUHONG NI, LU QUANKANG & HUA ZHONGYI | |
| The Phase-shift Problem in the EXAFS Data Analysis | 441 |
| ZHENG YU* | |
| Computer Simulations of Ar Behavior During AuCu Alloy Sputtering | 446 |
| F. Z. CUI*, W. Z. LI, Z. P. DONG, R. S. LI & Z. L. WANG | |
| A Study of the Interaction of Ar Ions with Au-Cu Alloy Surface by Observation of the Changes in Surface Composition | 452 |
| LI RISHENG* | |
| The Interaction Studies of V₂O₅ Supported on TiO₂ Surface by XPS | 458 |
| LIU ZHENXIANG*, BAO QIXUN, LI YUQING, XIE KAN & WU NAIJUAN | |

| | |
|---|------------|
| Comparison Between the Multiple-scattering and the Single-scattering Calculation for Azimuthal Photoelectron Diffraction TANG JINGCHANG* | 466 |
| LEED Intensity Measurements by Camera-Computer Method JIAHO LU*, SIMIN CHAI, CHINGHUA LIU, ZHIYUAN ZHANG YELIANG SHAN & NAN LI | 471 |
| An Automatic Laser Ellipsometer and its Application Software LUO JINSHENG, CHEN MINQI*, ZHU HUIXIAN & ZHANG RUIZHI | 477 |